Unit: mm

TOSHIBA Transistor Silicon PNP Epitaxial Type (PCT Process)

2SA1359

Audio Frequency Power Amplifier Low-Speed Switching

- Suitable for the output stage of 5-watt car radios and car stereos.
- Good hFE linearity
- Complementary to 2SC3422.

Absolute Maximum Ratings (Tc = 25°C)

Characteristics		Symbol	Rating	Unit	
Collector-base voltage		V_{CBO}	-40	V	
Collector-emitter voltage		V _{CEO}	-40	V	
Emitter-base voltage		V _{EBO}	-5	V	
Collector current		IC	-3	Α	
Base current		I _B	-1	Α	
Collector power dissipation	Ta = 25°C	Pc	1.5	W	
	Tc = 25°C	FC	10		
Junction temperature		Tj	150	°C	
Storage temperature range		T _{stg}	-55 to 150	°C	

8.3MAX.
5.8

9/3.1±0.1

1.0MAX.
1.9MAX.
0.75±0.15

1. EMITTER
2. COLLECTOR
3. BASE

JEDEC

JEITA

TOSHIBA
2-8H1A

Weight: 0.82 g (typ.)

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in

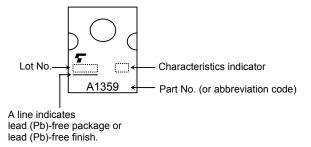
temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

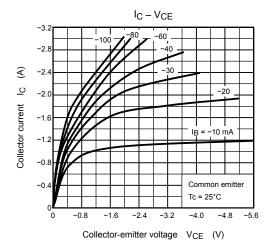
Electrical Characteristics (Tc = 25°C)

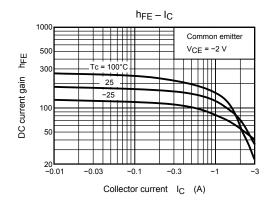
Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Collector cut-off current	I _{CBO}	V _{CB} = -40 V, I _E = 0	_	_	-100	nA
Emitter cut-off current	I _{EBO}	$V_{EB} = -5 \text{ V}, I_{C} = 0$	_	_	-100	nA
Collector-emitter breakdown voltage	V (BR) CEO	$I_C = -10 \text{ mA}, I_B = 0$	-40	-		٧
DC current gain	h _{FE (1)} (Note)	V _{CE} = -2 V, I _C = -0.5 A	80	-	240	
	h _{FE (2)}	V _{CE} = -2 V, I _C = -2.5 A	25	_	_	
Collector-emitter saturation voltage	V _{CE (sat)}	I _C = -2 A, I _B = -0.2 A	_	_	-0.8	V
Base-emitter voltage	V_{BE}	$V_{CE} = -2 \text{ V}, I_{C} = -0.5 \text{ A}$	_	_	-1.0	V
Transition frequency	f _T	V _{CE} = -2 V, I _C = -0.5 A	_	100	_	MHz
Collector output capacitance	C _{ob}	V _{CB} = -10 V, I _E = 0, f = 1 MHz	_	35	_	pF

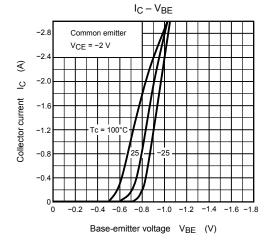
Note: $h_{FE\ (1)}$ classification O: 80 to 160, Y: 120 to 240

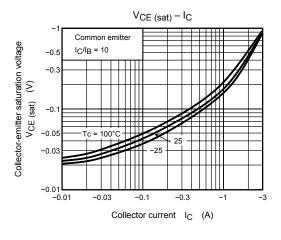
Marking

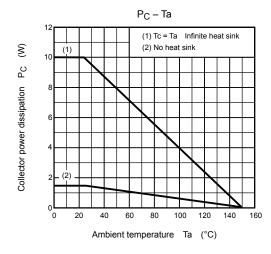


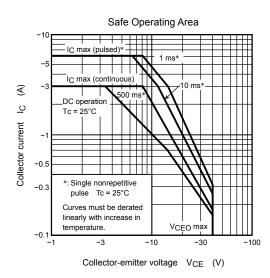












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20070701-EN

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